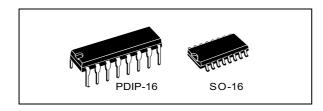


Single 8-channel analog multiplexer/demultiplexer

Datasheet - production data



Features

- Low "ON" resistance: 125 Ω (typ.)
- Over 15 V p.p signal-input range for V_{DD} - V_{FF} = 15 V
- High "OFF" resistance, channel leakage:
 ± 100 pA (typ.) at V_{DD} V_{EE} = 18 V
- · Binary address decoding on chip
- High degree of linearity: < 0.5 % distortion typ. at f_{IS} = 1 KHz, V_{IS} = 5 V_{pp}, V_{DD} - V_{SS} ≥ 10 V, R_I = 10 kΩ
- Very low quiescent power dissipation under all digital control input and supply conditions:
 0.2 μW (typ.) V_{DD} - V_{SS} = V_{DD} - V_{EE} = 10 V
- Matched switch characteristics:
 R_{ON} = 5 Ω(typ.) for V_{DD} V_{FF} = 15 V
- Wide range of digital and analog signal levels: digital 3 to 20, analog to 20 V p.p.
- Quiescent current specified up to 20 V
- 5 V, 10 V and 15 V parametric ratings
- ESD performance

HBM: 2 kVMM: 200 VCDM: 750 V

- Input leakage current I_I = 100 nA (max.) at V_{DD} = 18 V, T_A = 25 °C
- 100 % tested for quiescent current

Applications

- Automotive
- Industrial
- Computer
- Consumer

Description

The HCF4051 device is a monolithic integrated circuit fabricated in MOS (metal oxide semiconductor) technology available in SO-16 and PDIP-16 packages.

The HCF4051 analog multiplexer/demultiplexer is a digitally controlled analog switch having low ON impedance and very low OFF leakage current. This multiplexer circuit dissipates extremely low quiescent power over the full $_{\mbox{\scriptsize VDD}}$ - $\mbox{\scriptsize V}_{\mbox{\scriptsize SE}}$ supply voltage range, independent of the logic state of the control signals.

This device is a single 8-channel multiplexer having three binary control inputs, A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output. When a logic "1" is present at the inhibit input terminal all channels are off.

Table 1. Device summary

Order code	Temperature range	Package	Packaging	Marking
HCF4051M013TR	-55/+125 °C	SO-16	Tape and reel	HCF4051
HCF4051YM013TR ⁽¹⁾	-40/+125 °C	SO16 (automotive version)	Tape and Teel	HCF4051Y
HCF4051BEY	-55/+125 °C	PDIP-16	Tube	HCF4051BE

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

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HCF4051

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HCF4051 Pin information

1 Pin information

Figure 1. Pin connections (top view)

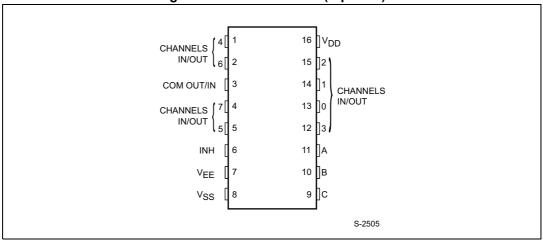


Table 2. Pin description

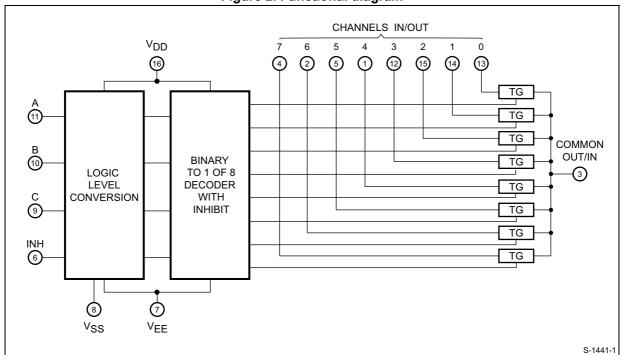
Pin no.	Symbol	Name and function
11, 10, 9	A, B, C	Binary control inputs
6	INH	Inhibit inputs
13, 14, 15, 12, 1, 5, 2, 4	0 to 7 channel IN/OUT	Independent inputs/outputs
3	COM OUT/IN	Common output/input
7	V _{EE}	Supply voltage
8	V _{SS}	Negative supply voltage
16	V_{DD}	Positive supply voltage

2 Functional description

Table 3. Truth table

Input	"ON" channel (S)			
Inhibit	С	В	Α	ON Chamiler (5)
0	0	0	0	0
0	0	0	1	1
0	0	1	0	2
0	0	1	1	3
0	1	0	0	4
0	1	0	1	5
0	1	1	0	6
0	1	1	1	7
1	Х	Х	Х	None

Figure 2. Functional diagram



INPUT V_{SS} cso3790

Figure 3. Input equivalent circuit



Electrical characteristics HCF4051

3 Electrical characteristics

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. All voltage values are referred to $V_{\rm SS}$ pin voltage.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DD}	Supply voltage	-0.5 to +22	V
VI	DC input voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC input current	±10	mA
В	Power dissipation per package	500 ⁽¹⁾	mW
P_{D}	Power dissipation per output transistor	100	IIIVV
T _{op}	Operating temperature	-55 to +125	°C
T _{stg}	Storage temperature	-65 to +150	C

^{1. 500} mW at 65 °C; derate to 300 mW by 10 mW/°C from 65 °C to 85 °C.

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V_{DD}	Supply voltage	3 to 20	V
V _I	Input voltage	0 to V _{DD}	V
T _{op}	Operating temperature	-55 to 125	°C

Table 6. DC specifications

			conditi					Value	9		
Symbol	Parameter	V	V	V	v	Т	_A = 25	°C	-55 to	125 °C	Unit
		V _{DD} (V)	Min.	Тур.	Max.	Min.	Max.				
	Quiagant davisa				5		0.04	5		150	
ال	Quiescent device current (all switches				10		0.04	10		300	μΑ
'L	ON or all switches OFF)				15		0.04	20		600	μΛ
	311)				20		0.08	100		3000	
Switch											
					5		470	1050		1200	
R_{ON}	Resistance	$0 \le V_I \le V_{DD}$	0	0	10		180	400		520	
					15		125	280		360	Ω
	Resistance ∆ _{RON}				5		10				
D _{ON}	(between any 2 of 4 switches)	$0 \le V_I \le V_{DD}$	0	0	10		10				
	,				15		5				
OFF ⁽¹⁾	Channel leakage current (all channels OFF) (COMMON O/I)		0	0	18		±0.1	100		1000	nA
OFF ⁽¹⁾	Channel leakage current (any channel OFF)		0	0	18		±0.1	100		1000	
C _I	Input capacitance						5				
C _O	Output capacitance		-5	-5	5		30				pF
C _{IO}	Feedthrough						0.2				
Control (address or inhibit)										
					5			1.5		1.5	
V_{IL}	Input low voltage		V _{EE} :	= V _{SS}	10			3		3	
		= V _{DD} through	to \	·1KΩ V _{SS}	15			4		4	V
		1 ΚΩ	I _{IS} <	2μΑ	5	3.5			3.5		v
V_{IH}	Input high voltage	nigh voltage		(on all OFF channels)		7			7]
					15	11			11		
I _{IH,} I _{IL}	Input leakage current	V _I = 0/	18 V		18		±10 ⁻³	±0.1		±1	μΑ
C _I	Input capacitance						5	7.5			pF

^{1.} Determined by minimum feasible leakage measurement for automating testing.

Electrical characteristics HCF4051

Table 7. Dynamic electrical characteristics $(T_{amb}$ = 25 °C, C_L = 50 pF, all input square wave rise and fall time = 20 ns)⁽¹⁾

(Tamb 20		-		Test co	nditio	n			Value		Unit
Parameter	V _{EE} (V)	R _L (K Ω)	f _I (KHz)	V _I (V)	V _{SS} (V)	V _{DD} (V)		Min.	Тур.	Max.	
						5			30	60	
Propagation delay time (signal input to output)		200		V _{DD}		10			15	30	ns
(**************************************						15			11	20	
Frequency response channel "ON"	=V _{SS}	1		5 ⁽²⁾		10	V _O at common OUT/IN		20		
(sine wave input) at 20 log V _O /V _I = -3 dB	- VSS	'		3		10	V _O at any channel		60		
Feedthrough (all channels OFF)	=V _{SS}	1		5 ⁽²⁾		10	V _O at common OUT/IN		12		MHz
at 20 log $V_O/V_I = -40 \text{ dB}$	- VSS	')		10	V _O at any channel		8		
Frequency signal crosstalk at 20 log $V_O/V_I = -40 \text{ dB}$	= V _{SS}	1		5 ⁽²⁾		10	Between any 2 channels		3		
				2 ⁽²⁾		5			0.3		
Sine wave distortion f _{IS} = 1 KHz sine wave	= V _{SS}	10	1	3 ⁽²⁾		10			0.2		%
10				5 ⁽²⁾		15			0.12		
Control (address or inhib	it)										
	0				0	5			360	720	
Propagation delay: address to signal OUT	0				0	10			160	320	
(channels ON or OFF)	0				0	15			120	240	
	-5				0	5			225	450	
	0				0	5			360	720	
Propagation delay: inhibit to signal OUT	0	1			0	10			160	320	ns
(channel turning ON)	0	'			0	15			120	240	113
	-10				0	5			200	400	
	0					5			200	450	
Propagation delay: inhibit to signal OUT	0	10				10			90	210	
(channel turning OFF)	0	.0				15			70	160	
	-10					5			130	300	
Address or inhibit to signal crosstalk	0	10 (1)			0	10	$V_C = V_{DD} - V_{SS}$ (square wave)		65		mV peak

^{1.} Both ends of channel.

Ay/

^{2.} Peak-to-peak voltage symmetrical about (V $_{\rm DD}$ - V $_{\rm EE}$) /2.

HCF4051 Electrical characteristics

 V_{DD} V_{DD} V_{DD} V_{DD} +15 V 7.5 V 5 V 5 V 0 0 0 0 5 V 5 V 7.5 V 16 16 16 16 0 0 ٧ss Vss 0 V_{SS} VEE 0 V 0 0 0 0 VEE VEEVEE0 8 8 8 -7.5 V -10 V -5 V V_{SS} 0 V S-1451 S-1452 S-1453 S-1454

Figure 4. Typical bias voltages

The ADDRESS (digital-control inputs) and INHIBIT logic levels are : "0" = V_{SS} and "1" = V_{DD} . The analog signal (through the TG) may swing from V_{EE} to V_{DD}

Special considerations

Control of analog signals up to 20 V peak-to-peak can be achieved by digital signal amplitudes of 4.5 to 20 V (if V_{DD} - V_{SS} = 3 V, a V_{DD} - V_{EE} of up to 13 V can be controlled; for V_{DD} - V_{EE} level differences above 13 V, a V_{DD} - V_{SS} of at least 4.5 V is required).

For example, if V_{DD} = +5, V_{SS} = 0, and V_{EE} = -13.5, analog signals from -13.5 V to 4.5 V can be controlled by digital inputs of 0 to 4.5 V. In certain applications, the external load resistor current may include both V_{DD} and signal-line components. To avoid drawing V_{DD} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8 V (calculated from R_{ON} values shown in *Table 6*: DC specifications). No V_{DD} current flows through R_L if the switch current flows into lead 3.

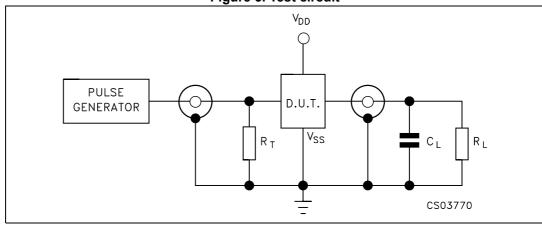


Figure 5. Test circuit

1. C_L = 50 pF or equivalent (includes jig and probe capacitance) R_L = 200 K Ω R_T = Z_{OUT} of pulse generator (typically 50 Ω).

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Figure 6. Waveform 1: channel turned ON (R_L = 1 K Ω , f = 1 MHz; 50 % duty cycle)

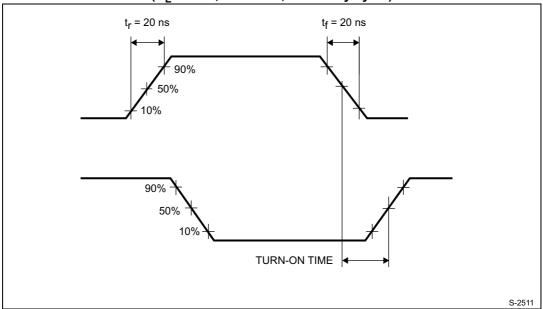
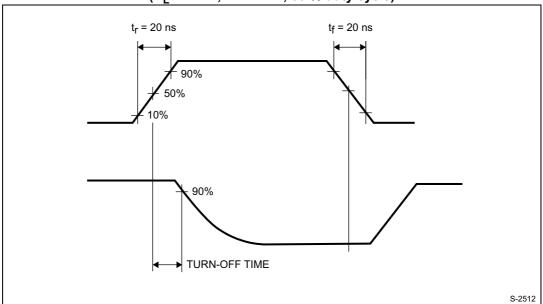


Figure 7. Waveform 2: channel turned OFF (R_L = 1 KW, f = 1 MHz; 50 % duty cycle)



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HCF4051 Package information

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



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Package information HCF4051

4.1 PDIP-16 (0.25) package information

Figure 8. PDIP-16 (0.25) package mechanical drawing

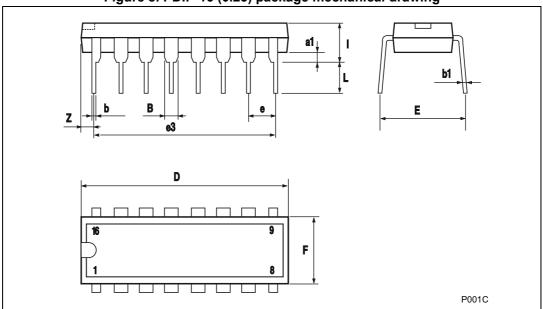


Table 8. PDIP-16 (0.25) package mechanical data

			Dimer	nsions		
Symbol		mm			inch	
	Min.	Тур.	Max.	Min.	Тур.	Max.
a1	0.51			0.020		
В	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

HCF4051 Package information

4.2 SO-16 package information

D M M PO13H

Figure 9. SO-16 package mechanical drawing

Table 9. SO-16 package mechanical data

			Dime:	nsions		
Symbol		mm			inch	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1			45°	(typ.)		
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.62			0.024
S			8 ° (max.)		



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Ordering information HCF4051

5 Ordering information

Table 10. Order codes

Order code	Temperature range	Package	Packaging	Marking
HCF4051M013TR	-55/+125 °C	SO-16		HCF4051
HCF4051YM013TR ⁽¹⁾	-40/+125 °C	SO16 (automotive version)	Tape and reel	HCF4051Y
HCF4051BEY	-55/+125 °C	PDIP-16	Tube	HCF4051BE

^{1.} Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

6 Revision history

Table 11. Document revision history

Date	Revision	Changes
26-Oct-2012	2	Updated Features (added ESD values), added Applications. Updated Table 1 (reformatted table, added order codes, temperature range, marking, updated package and packaging). Updated Description (unified part numbers, moved to page 2). Updated Section 2 to Section 4 (added titles and numbering). Updated Table 6 (removed -40/+85° temperature range). Reformatted Section 4 (added ECOPACK text, Figure 8, Figure 9, Table 8, and Table 9). Minor corrections throughout document.
30-Apr-2013	3	Updated Features (ESD values) Added Section 5: Ordering information

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